

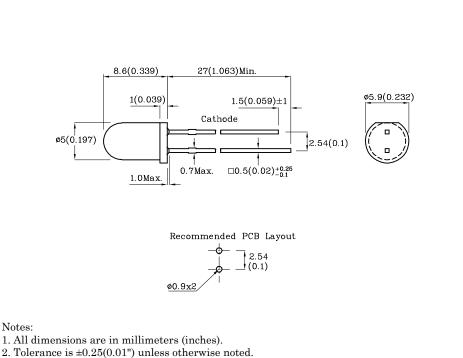
Part Number: XTHI12W

T-1 3/4 (5mm) Infrared Emitting Diode

Features

- Radial / Through hole package
- \bullet Reliable & robust
- Low power consumption
- Available on tape and reel
- \bullet RoHS Compliant





3. Specifications are subject to change without notice.

Package Schematics

Absolute Maximum Ratings		тні			
(T _A =25°C)		(GaAlAs)	Unit		
Reverse Voltage	V_{R}	5	V		
Forward Current	$I_{\rm F}$	50	mA		
Forward Current (Peak) 1/100 Duty Cycle 10µs Pulse Width	iFS	1200	mA		
Power Dissipation	P_{D}	85	mW		
Operating Temperature	$T_{\rm A}$	$-40 \sim +85$	°C		
Storage Temperature	Tstg	$-40 \sim +85$			
Lead Solder Temperature [2mm Below Package Base]	260°C For 3 Seconds				
Lead Solder Temperature [5mm Below Package Base]	260°C For 5 Seconds				

A Relative Humidity between 40% and 60% is recommended in ESD-protected work areas to reduce static build up during assembly process (Reference JEDEC/JESD625-A and JEDEC/J-STD-033)

Operating Characteristics (T _A =25°C)		THI (GaAlAs)	Unit	
Forward Voltage (Typ.) (I _F =20mA)	V_{F}	1.3	V	
Forward Voltage (Max.) (I _F =20mA)	V_{F}	1.6	V	
Reverse Current (Max.) (V _R =5V)	I_{R}	10	μΑ	
Wavelength of Peak Emission CIE127-2007* (Typ.) (I _F =20mA)	λP	880*	nm	
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =20mA)	$ riangle\lambda$	50	nm	
Capacitance (Typ.) (V _F =0V, f=1MHz)	С	90	pF	

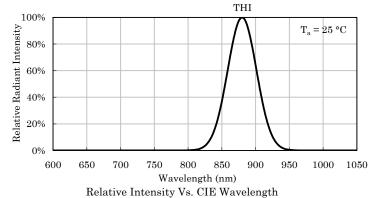
Part Number	Emitting Material	Lens-color	Radiant Intensity CIE127-2007* (Po=mW/sr) @20mA		CIE127-2007* CIE127-2007* (Po=mW/sr) (Po=mW/sr)		Wavelength CIE127-2007* nm λP	Viewing Angle 20 1/2
			min.	typ.	min.	typ.		
XTHI12W	GaAlAs	Water Clear	6*	14*	15*	39*	880*	20°

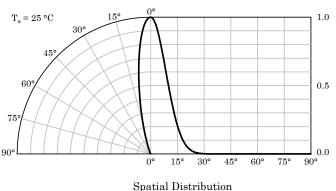
*Radiant intensity value and wavelength are in accordance with CIE127-2007 standards.

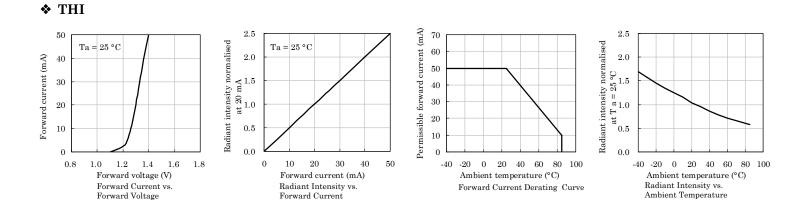
Mar 07,2023

XDSA7687 V9-Z Layout: Maggie L.









(°C)300 255°C/5 sec max 250 30°C 200 Temperature 150 4°C/s (100°C) 100 (85) 50 60 max 0 Time(sec) Notes:

I.Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C
2.Peak wave soldering temperature between 245°C ~ 255°C for 3 sec

(5 sec max).

3.Do not apply stress to the epoxy resin while the temperature is above 85° C. 4.Fixtures should not incur stress on the component when mounting and

during soldering process. 5.SAC 305 solder alloy is recommended.

6. No more than one wave soldering pass.

Wave Soldering Profile For Thru-Hole Products (Pb-Free Components)

Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux),

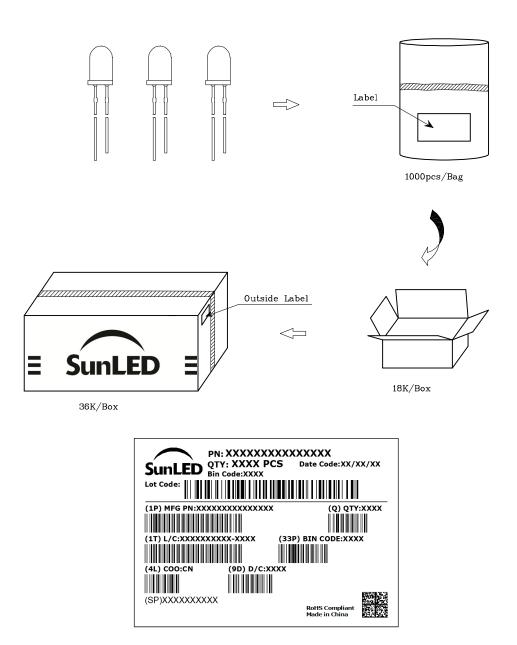
the typical accuracy of the sorting process is as follows:

- 1. Radiant Intensity / Luminous Flux: +/-15%
- 2. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.



PACKING & LABEL SPECIFICATIONS



TERMS OF USE

- 1. Data presented in this document reflect statistical figures and should be treated as technical reference only.
- 2. Contents within this document are subject to improvement and enhancement changes without notice.
- 3. The product(s) in this document are designed to be operated within the electrical and environmental specifications indicated on the datasheet. User accepts full risk and responsibility when operating the product(s) beyond their intended specifications.
- 4. The product(s) described in this document are intended for electronic applications in which a person's life is not reliant upon the LED. Please consult with a SunLED representative for special applications where the LED may have a direct impact on a person's life.
- 5. The performance of the product(s) should be evaluated and verified by the customer to ensure it can meet the customer's application requirements.
- 6. The contents within this document may not be altered without prior consent by SunLED.
- 7. Additional technical notes are available at https://www.SunLEDusa.com/TechnicalNotes.asp